

**20V PNP MEDIUM POWER TRANSISTOR IN SOT223**

**Features**

- $BV_{CE0} > -20V$
- $I_C = -6A$  High Continuous Collector Current
- $I_{CM} = -20A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(sat)}$
- $h_{FE}$  Specified up to  $-20A$  for a High Gain Hold-up
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/quality/product-definitions/) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

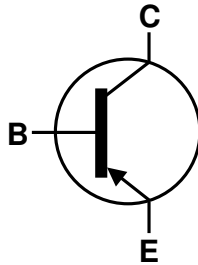
**Mechanical Data**

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208③
- Weight: 0.112 grams (Approximate)

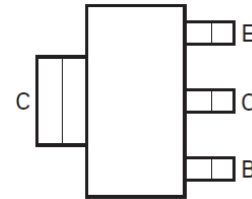
SOT223 (Type DN)



Top View



Device Symbol



Top View  
Pin-Out

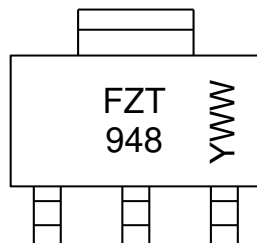
**Ordering Information** (Note 4)

Part Number	Compliance	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
						Qty.	Carrier
FZT948TA	Standard	SOT223 (Type DN)	FZT948	7	12	1,000	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

**Marking Information**

SOT223 (Type DN)



FZT948 = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 2 = 2022)  
 WW or  $\bar{W}W$  = Week Code (01 to 53)

### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-20	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-6	A
Peak Pulse Current	I <sub>CM</sub>	-20	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

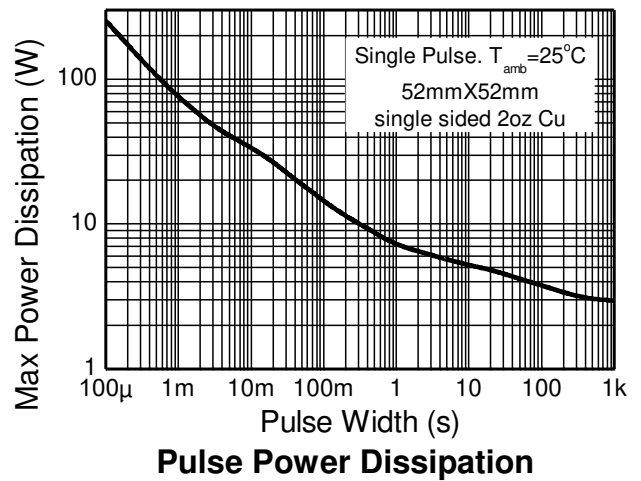
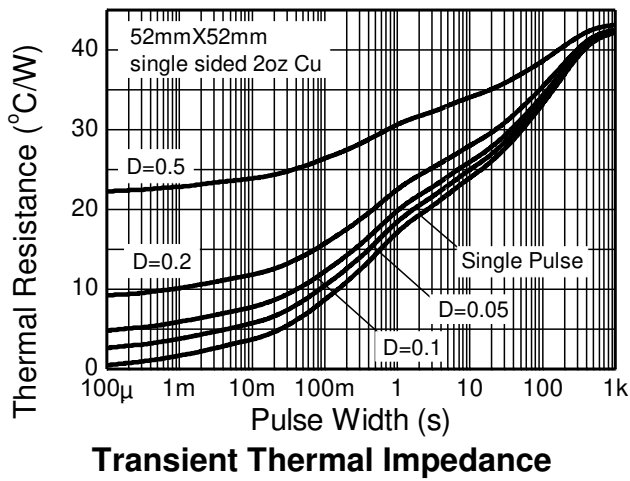
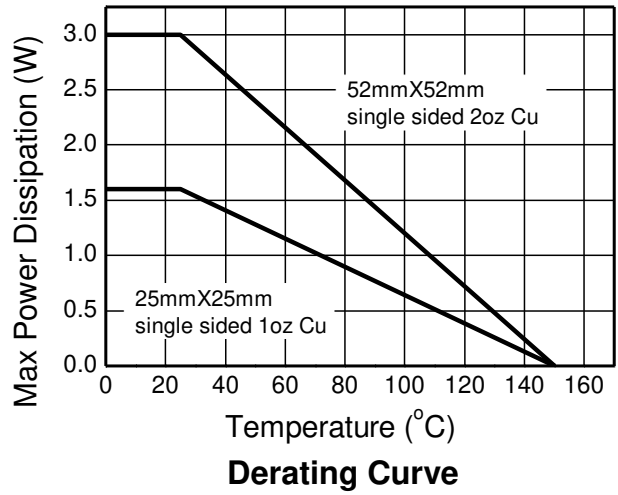
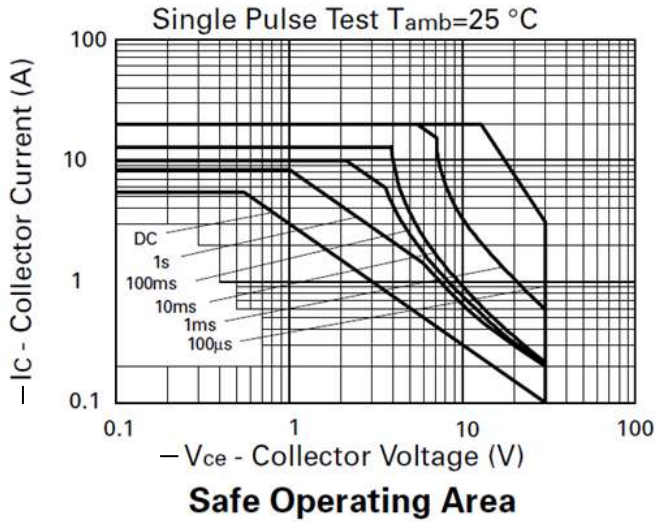
Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	3.0	W
		24	
Linear Derating Factor		1.6	mW/°C
		12.8	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub> (Note 5)	42	°C/W
	R <sub>θJA</sub> (Note 6)	78	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub> (Note 7)	8.84	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
  6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

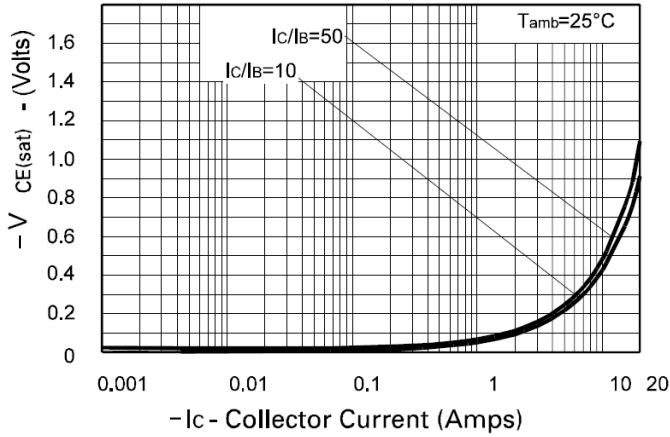


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

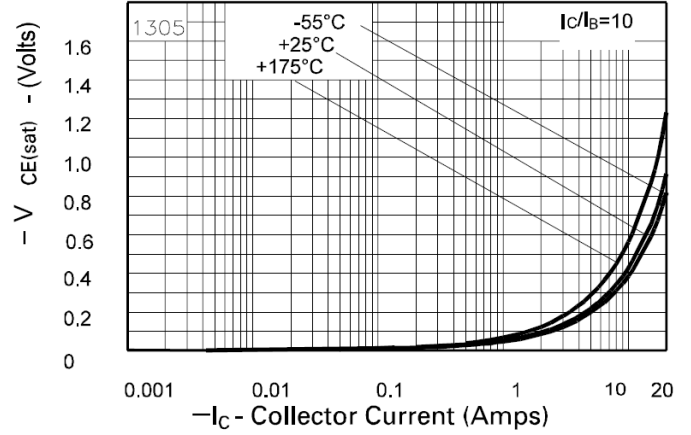
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-40	-55	—	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CER</sub>	-40	-55	—	V	I <sub>C</sub> = -1μA, R <sub>B</sub> ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-20	-30	—	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8	—	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current	I <sub>CBO</sub>	—	—	-50 -1	nA μA	V <sub>CB</sub> = -30V V <sub>CB</sub> = -30V, T <sub>A</sub> = +100°C
Collector Cut-Off Current	I <sub>CER</sub>	—	—	-50 -1	nA μA	V <sub>CE</sub> = -30V, R ≤ 1kΩ V <sub>CE</sub> = -30V, T <sub>A</sub> = +100°C
Emitter Cut-Off Current	I <sub>EBO</sub>	—	—	-10	nA	V <sub>EB</sub> = -6V
DC Current Transfer Static Ratio (Note 9)	h <sub>FE</sub>	100	200	—	—	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -1V
		100	200	300		I <sub>C</sub> = -1A, V <sub>CE</sub> = -1V
		75	160	—		I <sub>C</sub> = -5A, V <sub>CE</sub> = -1V
		60	130	—		I <sub>C</sub> = -10A, V <sub>CE</sub> = -1V
		15	40	—		I <sub>C</sub> = -20A, V <sub>CE</sub> = -2V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	—	-60	-130	mV	I <sub>C</sub> = -0.5A, I <sub>B</sub> = -10mA
		—	-110	-180		I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
		—	-200	-280		I <sub>C</sub> = -4A, I <sub>B</sub> = -400mA
		—	-360	-450		I <sub>C</sub> = -6A, I <sub>B</sub> = -250mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	—	-1,050	-1,200	mV	I <sub>C</sub> = -5A, I <sub>B</sub> = -300mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	—	-870	-1,050	mV	I <sub>C</sub> = -6A, V <sub>CE</sub> = -1V
Transitional Frequency (Note 9)	f <sub>T</sub>	—	80	—	MHz	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V f = 50MHz
Output Capacitance	C <sub>obo</sub>	—	163	—	pF	V <sub>CB</sub> = -10V, f = 1MHz
Switching Time	t <sub>on</sub>	—	120	—	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -4A I <sub>B1</sub> = -I <sub>B2</sub> = -400mA
	t <sub>off</sub>	—	126	—		

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

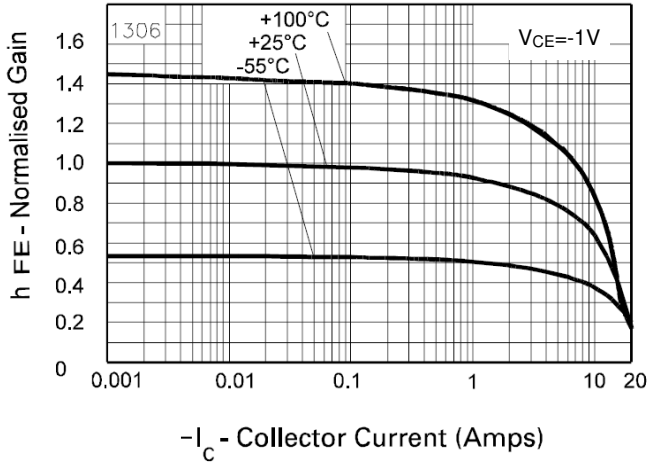
**Typical Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)



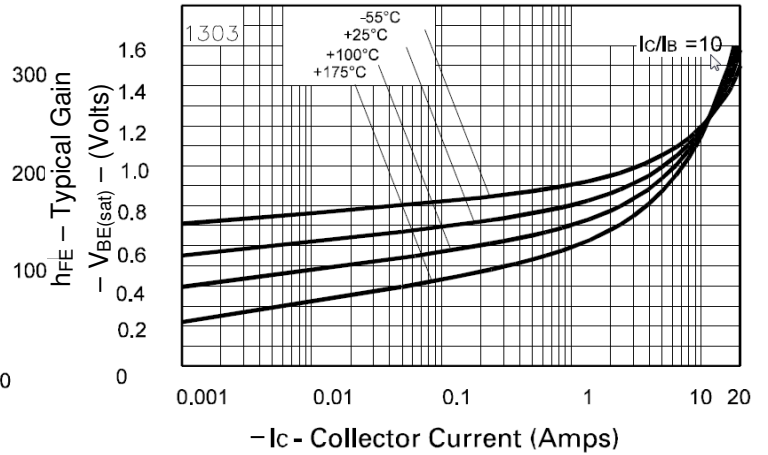
**VCE(sat) v IC**



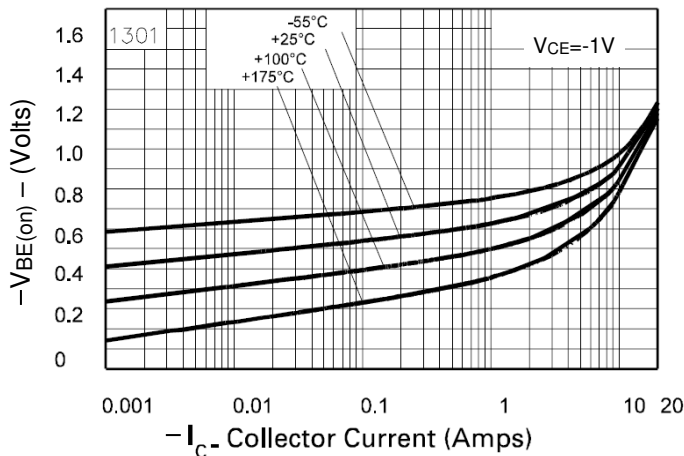
**VCE(sat) v IC**



**hFE v IC**



**VBE(sat) v IC**

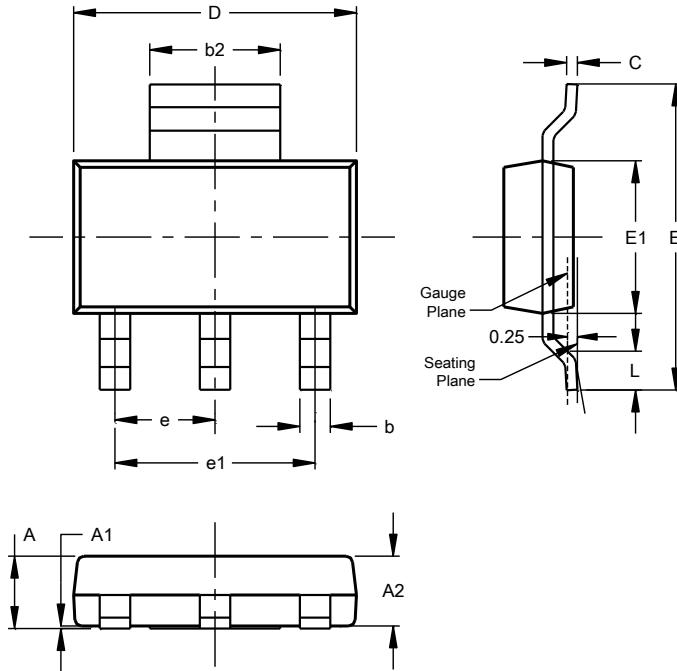


**VBE(on) v IC**

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SOT223 (Type DN)

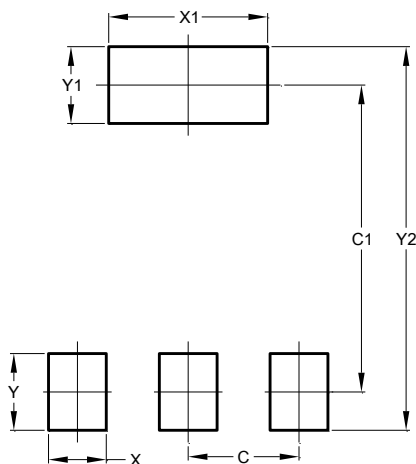


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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